New Jersey Semi-Conductor Products, Inc.

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## ICTE5 thru ICTE18C, 1N6373 thru 1N6386

## **TRANSZORB® Transient Voltage Suppressors**



Case Style 1.5KE

PRIMARY CHARACTERISTICS				
V <sub>WM</sub>	5.0 V to 18 V			
P <sub>PPM</sub>	1500 W			
PD	6.5 W			
IFSM	200 A			
T <sub>J</sub> max.	175 °C			

#### **TYPICAL APPLICATIONS**

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial and telecommunication.

#### **DEVICES FOR BI-DIRECTION APPLICATIONS**

For bi-directional types, use C suffix (e.g. ICTE18C). Electrical characteristics apply in both directions.

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Peak pulse power dissipation with a 10/1000 µs waveform <sup>(1)</sup> (fig. 1)	P <sub>PPM</sub>	1500	W		
Peak pulse current with a 10/1000 μs waveform <sup>(1)</sup> (fig. 3)	PPM	See next table	A		
Power dissipation on infinite heatsink at $T_L = 75 \ ^{\circ}C$ (fig. 8)	P <sub>D</sub>	6.5	w		
Peak forward surge current 8.3 ms single half sine-wave uni-directional only <sup>(2)</sup>	I <sub>FSM</sub>	200	A		
Maximum instantaneous forward voltage at 100 A for uni-directional only	V <sub>F</sub>	3.5	V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175	°C		



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

### **Quality Semi-Conductors**

# ICTE5 thru ICTE18C, 1N6373 thru 1N6386

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ELECTRICAL CHARACTERISTICS (JEDEC REGISTERED DATA) (T <sub>A</sub> = 25 °C unless otherwise noted)							
JEDEC TYPE NUMBER	GENERAL SEMICONDUCTOR PART NUMBER	STAND-OFF VOLTAGE V <sub>WM</sub> (V)	MINIMUM BREAKDOWN VOLTAGE AT 1.0 mA V <sub>BR</sub> (V)	MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub> I <sub>D</sub> (µA)	$\begin{array}{c} \textbf{MAXIMUM}\\ \textbf{CLAMPING}\\ \textbf{VOLTAGE}\\ \textbf{AT I_{PP}}=1.0 \text{ A}\\ \textbf{V_C} (V) \end{array}$	MAXIMUM CLAMPING VOLTAGE AT I <sub>PP</sub> = 10 A V <sub>C</sub> (V)	MAXIMUM PEAK PULSE CURRENT I <sub>PP</sub> (A)
UNI-DIRECTION	IAL TYPES		I	· · · · · · · · · · · · · · · · · · ·			
1N6373 <sup>(2)</sup>	ICTE5 <sup>(2)</sup>	5.0	6.0	300	7.1	7.5	160
1N6374	ICTE8	8.0	9.4	25.0	11.3	11.5	100
1N6375	ICTE10	10.0	11.7	2.0	13.7	14.1	90
1N6376	ICTE12	12.0	14.1	2.0	16.1	16.5	70
1N6377	ICTE15	15.0	17.6	2.0	20.1	20.6	60
1N6378	ICTE18	18.0	21.2	2.0	24.2	25.2	50
<b>BI-DIRECTIONA</b>	L TYPES						
1N6382	ICTE8C	8.0	9.4	50.0	11.4	11.6	100
1N6383	ICTE10C	10.0	11.7	2.0	14.1	14.5	90
1N6384	ICTE12C	12.0	14.1	2.0	16.7	17.1	70
1N6385	ICTE15C	15.0	17.6	2.0	20.8	21.4	60
1N6386	ICTE18C	18.0	21.2	2.0	24.8	25.5	50

Notes

(1) "C" suffix indicates bi-directional

(2) ICTE5 and 1N6373 are not available as bi-directional

(3) Clamping factor: 1.33 at full rated power; 1.20 at 50 % rated power; clamping factor: the ratio of the actual V<sub>C</sub> (clamping voltage) to the V<sub>BR</sub> (breakdown voltage) as measured on a specific device

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ICTE5-E3/54	0.968	54	1400	13" diameter paper tape and reel		
ICTE5HE3/54 (1)	0.968	54	1400	13" diameter paper tape and reel		

Note

(1) Automotive grade